

Monolayer V_2MX_4 : A new family of quantum anomalous Hall insulators Yadong Jiang¹, Huan Wang¹, Kejie Bao¹ and Jing Wang^{1,2,3}

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Monolayer V_2MX_4 family: FM ground state, C = -1 QAH, large gap



0.0

-0.2

-0.4

The magnetic ground state of the 2D materials class is FM along z direction Spin magnetic moment ~2.6 (1.3) μ_B per V (Ti) atom. FM From :

- 1. Direct exchange between V(Ti) pairs due to Hund's rule. (1NN)
- Super-exchange from V(Ti)-M-V(Ti). (2NN)

Materials	a (Å)	T_c (K)	MAE (meV)	$E_g \; (\mathrm{meV})$
V_2WS_4	5.74	470	12.1	279
V_2WSe_4	5.82	440	13.2	258
V_2MoS_4	5.72	310	2.0	115
V_2MoSe_4	5.83	284	2.2	70
$\mathrm{Ti}_{2}\mathrm{WS}_{4}$	5.75	240	10.7	259
$\mathrm{Ti}_{2}\mathrm{WSe}_{4}$	5.79	210	13.7	275

TABLE I. Lattice constant, MAE per unit cell, Curie temperature T_c from Monte Carlo simulations, and band gap E_q from using the Heyd-Scuseria-Ernzerhof hybrid functional method [51] (Fig. S4).





0.0

-0.4

0.0

-0.4E



4. Physics Review Letter. **122**, 206401(2019)







